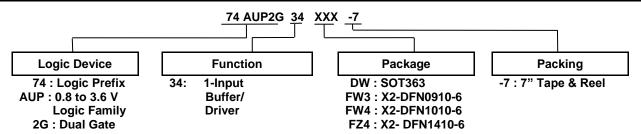


Ordering Information



Part Number	Package	Package	Package	7" Tape	and Reel
Fait Number	Code	(Notes 4 & 5)	Size	Quantity	Part Number Suffix
74AUP2G34DW-7	DW	SOT363	2.0mm X 2.0mm X 1.1mm 0.65 mm lead pitch	3000/Tape & Reel	-7
74AUP2G34FW3-7	FW3	X2-DFN0910-6	0.9mm X 1.0mm X 0.35mm 0.35 mm pad pitch	5000/Tape & Reel	-7
74AUP2G34FW4-7	FW4	X2-DFN1010-6	1.0mm X 1.0mm X 0.4mm 0.35 mm pad pitch	5000/Tape & Reel	-7
74AUP2G34FZ4-7	FZ4	X2-DFN1410-6	1.4mm X 1.0mm X 0.4mm 0.5 mm pad pitch	5000/Tape & Reel	-7

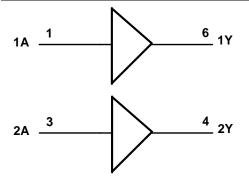
Notes: 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

5. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

Pin Descriptions

Pin Name	Pin No.	Function				
1A	1	Data Input				
GND	2	Ground				
2A	3	Data Input				
2Y	4	Data Output				
Vcc	5	Supply Voltage				
1Y	6	Data Output				

Logic Diagram



Function Table

Inputs	Outputs
Α	Υ
Н	Н
L	L



Absolute Maximum Ratings (Notes 6,7) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range	-0.5 to +4.6	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < 0	50	mA
I _{OK}	Output Clamp Current (V _O < 0)	-50	mA
Io	Continuous Output Current (V _O = 0 to V _{CC})	±20	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

Recommended Operating Conditions (Note 8) (@T_A = +25°C, unless otherwise specified.)

Symbol		Parameter	Min	Max	Unit
V_{CC}	Operating Voltage		0.8	3.6	V
V_{I}	Input Voltage		0	3.6	V
Vo	Output Voltage		0	V _{CC}	V
		$V_{CC} = 0.8V$	_	-20	μΑ
		V _{CC} = 1.1V	_	-1.1	
	High Loyal Output Current	$V_{CC} = 1.4V$	_	-1.7	
Іон		V _{CC} = 1.65V	_	-1.9	mA
		$V_{CC} = 2.3V$	_	-3.1	
		$V_{CC} = 3.0V$	_	-4	
		$V_{CC} = 0.8V$	_	20	μΑ
		V _{CC} = 1.1V	_	1.1	
Les	Low Lovel Output Current	O 3.6 O V _{CC}			
$V_{CC} = 1.65V \\ V_{CC} = 2.3V \\ V_{CC} = 3.0V \\ V_{CC} = 3.0V \\ V_{CC} = 0.8V \\ V_{CC} = 1.1V \\ V_{CC} = 1.4V \\ V_{CC} = 1.65V \\ V_{CC} = 2.3V \\ -$	1.9	mA			
	$V_{CC} = 2.3V$	_	3.1		
		$V_{CC} = 3.0V$	_	4	
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 0.8V to 3.6V		200	ns/V
T _A	Operating Free-Air Temperature	1	-40	+125	°C

Note:

8. Unused inputs should be held at $V_{\mbox{\footnotesize CC}}$ or Ground.

^{6.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

^{7.} Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	T _A = -	+25°C	T _A = -40	to +85°C	Unit	
Symbol	Parameter	rest Conditions	Vcc	Min	Max	Min	Max	Unit	
		_	0.8V to 1.65V	0.80 X V _{CC}	_	0.80 X V _{CC}	_		
V_{IH}	High-Level Input	_	1.65V to 1.95V	0.65 X V _{CC}	_	0.65 X V _{CC}	_	V	
VIH	Voltage	_	2.3V to 2.7V	1.6	_	1.6	_	V	
		_	3.0V to 3.6V	2.0	_	2.0	_		
		_	0.8V to 1.65V	_	0.30 X V _{CC}	_	0.30 X V _{CC}		
VIL	Low-Level Input	_	1.65V to 1.95V	_	0.35 X V _{CC}	_	0.35 X V _{CC}	V	
V IL	Voltage	_	2.3V to 2.7V	_	0.7	_	0.7	·	
		_	3.0V to 3.6V	_	0.9	_	0.9		
		$I_{OH} = -20\mu A$	0.8V to 3.6V	V _{CC} – 0.1	_	V _{CC} – 0.1	_		
		$I_{OH} = -1.1 \text{mA}$	1.1V	0.75 X V _{CC}	_	0.7 X V _{CC}	_		
		$I_{OH} = -1.7 \text{mA}$	1.4V	1.11	_	1.03	_		
\ /	High-Level	I _{OH} = -1.9mA	1.65V	1.32	_	1.3	_	V	
V _{OH}	Output Voltage	I _{OH} = -2.3mA	0.01/	2.05	_	1.97	_	V	
		I _{OH} = -3.1mA	2.3V	1.9	_	1.85	_		
		I _{OH} = -2.7mA	0) /	2.72	_	2.67	_		
		I _{OH} = -4mA	3V	2.6	_	2.55	_		
		$I_{OL} = 20\mu A$	0.8V to 3.6V	_	0.1	_	0.1		
		I _{OL} = 1.1mA	1.1V	_	0.3 X V _{CC}	_	0.3 X V _{CC}		
		I _{OL} = 1.7mA	1.4V	_	0.31	_	0.37		
.,	Low-Level Input	I _{OL} = 1.9mA	1.65V	_	0.31	_	0.35	.,	
VoL	Voltage	I _{OL} = 2.3mA	0.01/	_	0.31	_	0.33	V	
		I _{OL} = 3.1mA	2.3V	_	0.44	_	0.45		
		I _{OL} = 2.7mA		_	0.31	_	0.33		
		I _{OL} = 4mA	3V	_	0.44	_	0.45		
lı	Input Current	A or B Input V _I = GND to 3.6V	0V to 3.6V	_	± 0.1	_	± 0.5	μA	
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0V	_	± 0.2	_	± 0.6	μΑ	
Δl _{OFF}	Delta Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0V to 0.2V	_	± 0.2	_	± 0.6	μΑ	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC},$ $I_O = 0$	0.8V to 3.6V	_	0.5	_	0.9	μА	
ΔI _{CC}	Additional Supply Current	One input at V_{CC} –0.6V Other input at V_{CC} or GND	3.3V	_	40	_	50	μА	



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V _{CC}	T _A = -40 t	to +125°C	Unit
Symbol	i arameter	rest conditions	V CC	Min	Max	Oille
		_	0.8V to 1.65V	0.80 X V _{CC}	_	
V _{IH}	High-Level Input Voltage	_	1.65V to 1.95V	0.70 X V _{CC}	_	V
VIH	r light-Level input voltage	_	2.3V to 2.7V	1.6	_	V
		_	3.0V to 3.6V	2.0	_	
		_	0.8V to 1.65V	_	0.25 X V _{CC}	
V_{IL}	Low-Level Input Voltage	_	1.65V to 1.95V	_	0.30 X V _{CC}	V
V IL	Low Love input vertage	_	2.3V to 2.7V	_	0.7	
		_	3.0V to 3.6V	_	0.9	
		$I_{OH} = -20\mu A$	0.8V to 3.6V	V _{CC} – 0.11	_	
		$I_{OH} = -1.1 \text{mA}$	1.1V	0.6 X V _{CC}	_	
		$I_{OH} = -1.7 \text{mA}$	1.4V	0.93	_	
	High Lovel Output Valtage	I _{OH} = -1.9mA	1.65V	1.17	_	.,
Vон	High Level Output Voltage	$I_{OH} = -2.3$ mA	0.01/	1.77	_	V
		I _{OH} = -3.1mA	2.3V	1.67	_	
		I _{OH} = -2.7mA	21/	2.40	_	
		I _{OH} = -4mA	3V	2.30	_	
		$I_{OL} = 20\mu A$	0.8V to 3.6V	_	0.11	
		I _{OL} = 1.1mA	1.1V	_	0.33 X V _{CC}	
		$I_{OL} = 1.7 \text{mA}$	1.4V	_	0.41	
	Lave Lavel Imput Valtage	I _{OL} = 1.9mA	1.65V	_	0.39	V
V_{OL}	Low-Level Input Voltage	$I_{OL} = 2.3 \text{mA}$	2.3V	_	0.36	V
		I _{OL} = 3.1mA	2.3V	_	0.50	
		$I_{OL} = 2.7 \text{mA}$	01/	_	0.36	
		I _{OL} = 4mA	3V	_	0.50	
lı	Input Current	A or B Input V _I = GND to 3.6V	0V to 3.6V	_	± 0.75	μΑ
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V	_	± 1.0	μΑ
ΔI_{OFF}	Delta Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V to 0.2V	_	± 2.5	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	0.8V to 3.6V	_	1.4	μA
ΔI_{CC}	Additional Supply Current	Input at V _{CC} –0.6V Other input at V _{CC} or GND	3.3V	_	75	μА

Operating and Package Characteristics

 $T_A = +25$ °C

F	Parameter	Test Conditions	Vcc	Тур	Unit	
			0.8V	5.1		
			1.2V ± 0.1V	5.2		
0	C_{pd} Power dissipation $f = 1 MHz$ No Load	f = 1MHz	1.5V ± 0.1V	5.2		
C_{pd}		No Load	1.8V ± 0.15V	5.5	pr	
		2.5V ± 0.2V	5.7			
			$ \begin{array}{c cccc} $			
Cı	Input Capacitance	$V_i = V_{CC}$ or GND	0V or 3.3V	2.0	pF	
Co	Output Capacitance	V _O = V _{CC} or GND	0V	2.0	pF	



Switching Characteristics

 $C_L = 5pF$ see Figure 1

Parameter	From	TO OUTPUT	V		T _A = +25°C			T _A = -40 to +85°C		T _A = -40 to +125°C	
i arameter	Input		V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
			0.8V	_	14.9	_	_	_	_	_	
			1.2V ± 0.1V	2.6	4.7	10.1	2.0	11.1	2.0	12.2	ns
	۸	Y	1.5V ± 0.1V	2.1	3.4	5.7	1.6	6.5	1.6	7.2	
t _{pd}	А		1.8V ± 0.15V	1.8	2.9	4.5	1.4	5.2	1.4	5.8	
			2.5V ± 0.2V	1.5	2.3	3.5	1.2	4.2	1.2	4.6	
			$3.3V \pm 0.3V$	1.4	2.1	3.2	1.0	3.8	1.0	4.2	

 $C_L = 10pF$ see Figure 1

Parameter	From	то	V		T _A = +25°C			$T_A = -40 \text{ to } +85^{\circ}\text{C}$		T _A = -40 to +125°C	
Farameter	Input OUTPUT	OUTPUT	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
		0.8V	_	18.4	_	_	_	_	_		
			1.2V ± 0.1V	3.2	5.6	11.8	2.3	12.8	2.3	13.5	1
	۸	V	1.5V ± 0.1V	2.6	4.1	6.7	1.9	7.7	1.9	8.5]
t _{pd} A	Ť	1.8V ± 0.15V	2.3	3.4	5.3	1.7	6.2	1.7	6.9	ns	
			2.5V ± 0.2V	2.0	2.9	4.2	1.5	5.0	1.5	5.5	1
			3.3V ± 0.3V	1.7	2.6	3.8	1.4	4.6	1.4	5.1	1

C_L = 15pF see Figure 1

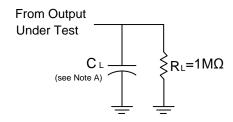
Parameter	From	TO OUTPUT	.,		T _A = +25°C			$T_A = -40 \text{ to } +85^{\circ}\text{C}$		$T_A = -40 \text{ to } +125^{\circ}\text{C}$	
Input	Input		Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
			0.8V	_	21.9	_	_	_	_	_	
			1.2V ± 0.1V	3.6	6.4	13.8	2.6	15.7	2.6	15.9	1
	_	Y	1.5V ± 0.1V	3.0	4.6	7.6	2.2	8.9	2.2	9.8]
t _{pd} A	A		1.8V ± 0.15V	2.6	3.9	6.0	2.0	7.2	2.0	7.9	ns
			2.5V ± 0.2V	2.3	3.3	4.8	1.8	5.7	1.8	6.3	
			3.3V ± 0.3V	1.8	3.1	4.2	1.6	5.0	1.6	5.5	

 $C_L = 30pF$ see Figure 1

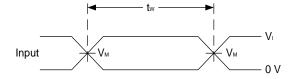
Parameter	From	то	V		T _A = +25°C			T _A = -40 to +85°C		T _A = -40 to +125°C	
Input	OUTPUT	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit	
			V8.0	_	32.1	_	_	_	_	_	
		Y	1.2V ± 0.1V	4.8	8.7	16.3	3.6	18.9	3.6	20.8	ns
	۸		1.5V ± 0.1V	4.0	6.2	10.3	3.4	12.2	3.4	13.4	
ι _{pd}	t _{pd} A		1.8V ± 0.15V	3.6	5.2	8.1	3.2	9.8	3.2	10.8	
			2.5V ± 0.2V	2.4	4.4	6.4	2.3	7.7	2.3	8.5	
			$3.3V \pm 0.3V$	2.2	4.2	5.6	2.1	6.5	2.1	7.2	



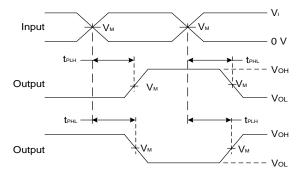
Parameter Measurement Information



	Inputs		V	•
V _{CC}	VI	t _r /t _f	V _M	CL
0.8V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.2V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.5V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.8V±0.15V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
2.5V±0.2V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1 Load Circuit and Voltage Waveforms

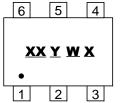
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD.}}$



Marking Information

(1) SOT363



74AUP2G34DW-7

XX: Identification code

Y : Year 0~9

W: Week: A~Z: 1~26 week;

a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Internal Code

Part Number	Package	Identification Code

SOT363

(2) X2-DFN1410-6, X2-DFN1010-6, X2-DFN0910-6

(Top View)

 \underline{XX} : Identification Code \underline{Y} : Year: $0 \sim 9$

W: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

ST

52 and 53 week

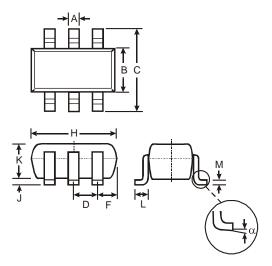
X: A~Z: Internal code

Part Number	Package	Identification Code
74AUP2G34FZ4-7	X2-DFN1410-6	RT
74AUP2G34FW4-7	X2-DFN1010-6	ST
74AUP2G34FW3-7	X2-DFN0910-6	MT

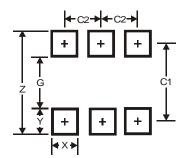


SOT363 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT363				
Dim	Min	Max	Тур		
Α	0.10	0.30	0.25		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D		0.65 Ty	р		
F	0.40	0.45	0.425		
Н	1.80	2.20	2.15		
J	0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
M	0.10	0.22	0.11		
α	0°	8°	-		
All Dimensions in mm					

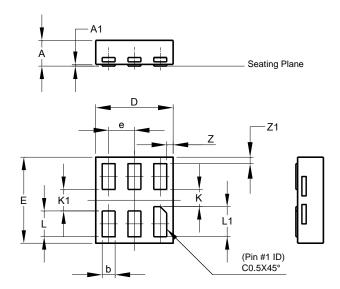


Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65

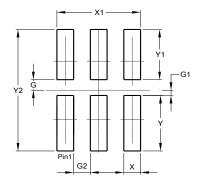


X2-DFN0910-6 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN0910-6				
Dim	Min	Max	Тур	
Α	-	0.35	0.30	
A1	0	0.03	0.02	
b	0.10	0.20	0.15	
D	0.85	0.95	0.90	
Е	0.95	1.05	1.00	
е	-	-	0.30	
K	0.20	-	-	
K1	0.25	-	1	
L	0.25	0.35	0.30	
L1	0.30	0.40	0.35	
Z	-	-	0.075	
Z 1	-	-	0.075	
All Dimensions in mm				

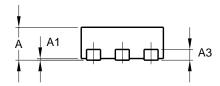


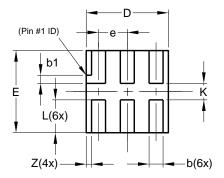
Dimensions	Value (in mm)
G	0.100
G1	0.050
G2	0.150
X	0.150
X1	0.750
Y	0.525
Y1	0.475
Y2	1.150



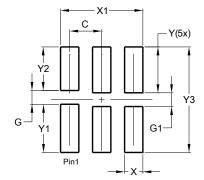
X2-DFN1010-6 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.





X2-DFN1010-6				
Dim	Min	Max	Тур	
Α		0.40	0.39	
A1	0.00	0.05	0.02	
A3			0.13	
b	0.14	0.20	0.17	
b1	0.05	0.15	0.10	
D	0.95	1.05	1.00	
Е	0.95	1.05	1.00	
е	_	_	0.35	
L	0.35	0.45	0.40	
K	0.15			
Z			0.065	
All Dimensions in mm				

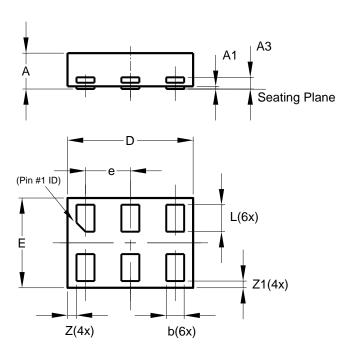


Dimensions	Value (in mm)
С	0.350
G	0.150
G1	0.150
Х	0.200
X1	0.900
Y	0.500
Y1	0.525
Y2	0.475
Y3	1.150

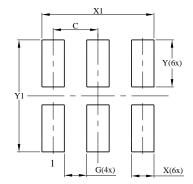


X2-DFN1410-6 Package Outline Dimensions and Suggested Pad Layout

 $Please see AP02002 \ at \ http://www.diodes.com/datasheets/ap02002.pdf \ for \ the \ latest \ version.$



X2-DFN1410-6			
Dim	Min	Max	Тур
Α		0.40	0.39
A1	0.00	0.05	0.02
A3			0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
е			0.50
L	0.25	0.35	0.30
Z			0.10
Z1	0.045	0.105	0.075
All Dimensions in mm			



Dimensions	Value (in mm)
С	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250



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